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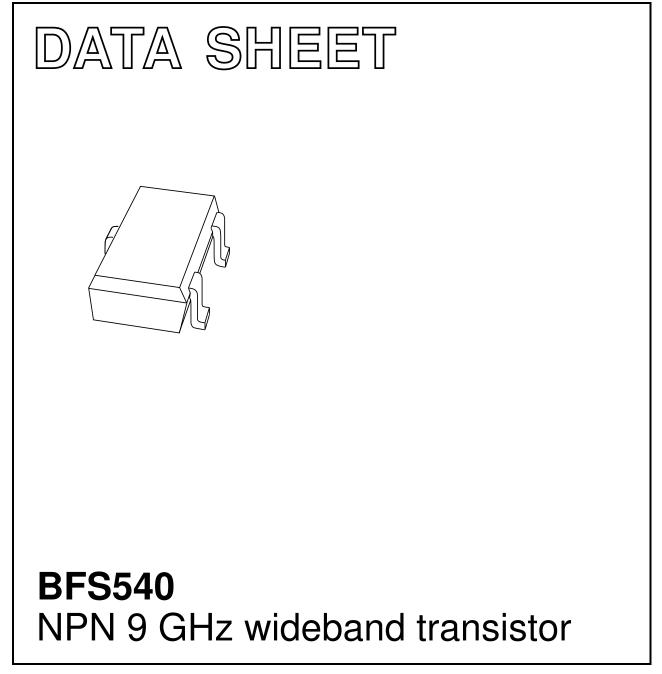


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DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1997 Dec 05 2000 May 30



FEATURES

- High power gain
- Low noise figure
- · High transition frequency
- · Gold metallization ensures excellent reliability
- SOT323 package.

APPLICATIONS

RF wideband amplifier applications such as satellite TV systems and RF portable communication equipment with signal frequencies up to 2 GHz.

QUICK REFERENCE DATA

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---|---------------------------|--|------|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | - | - | 20 | V |
| V _{CEO} | collector-emitter voltage | open base | _ | - | 15 | V |
| I _C | DC collector current | | - | - | 120 | mA |
| P _{tot} | total power dissipation | $T_s \le 80 \text{ °C}; \text{ note } 1$ | - | - | 500 | mW |
| h _{FE} | DC current gain | $I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; T_{j} = 25 \text{ °C}$ | 100 | 120 | 250 | |
| f _T | transition frequency | $I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 1 \text{ GHz};$ $T_{amb} = 25 \text{ °C}$ | - | 9 | - | GHz |
| G _{UM} maximum unilateral power gain | | $I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 900 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$ | - | 14 | - | dB |
| F | noise figure | $I_{C} = 10 \text{ mA}; V_{CE} = 8 \text{ V}; f = 900 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$ | - | 1.3 | 1.7 | dB |

Note

1. T_s is the temperature at the soldering point of the collector tab.

LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|--|-----------------------------------|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | _ | 20 | V |
| V _{CES} | s collector-emitter voltage $R_{BE} = 0$ | | _ | 15 | V |
| V _{EBO} | emitter-base voltage | open collector | _ | 2.5 | V |
| I _C | DC collector current | | - | 120 | mA |
| P _{tot} | total power dissipation | $T_s \le 80 \ ^{\circ}C$; note 1 | - | 500 | mW |
| T _{stg} | storage temperature | | -65 | 150 | °C |
| Tj | junction temperature | | - | 175 | °C |

2

Note

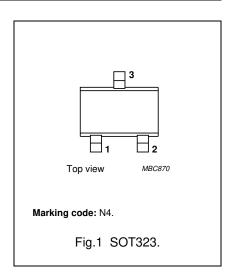
1. T_s is the temperature at the soldering point of the collector tab.

DESCRIPTION

NPN transistor in a SOT323 plastic package.

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | base |
| 2 | emitter |
| 3 | collector |



Product specification

BFS540

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|---------------------|---|----------------------------------|-------|------|
| R _{th j-s} | thermal resistance from junction to soldering point | $T_s \le 80 \ ^\circ C$; note 1 | 190 | K/W |

Note

1. T_s is the temperature at the soldering point of the collector tab.

CHARACTERISTICS

 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

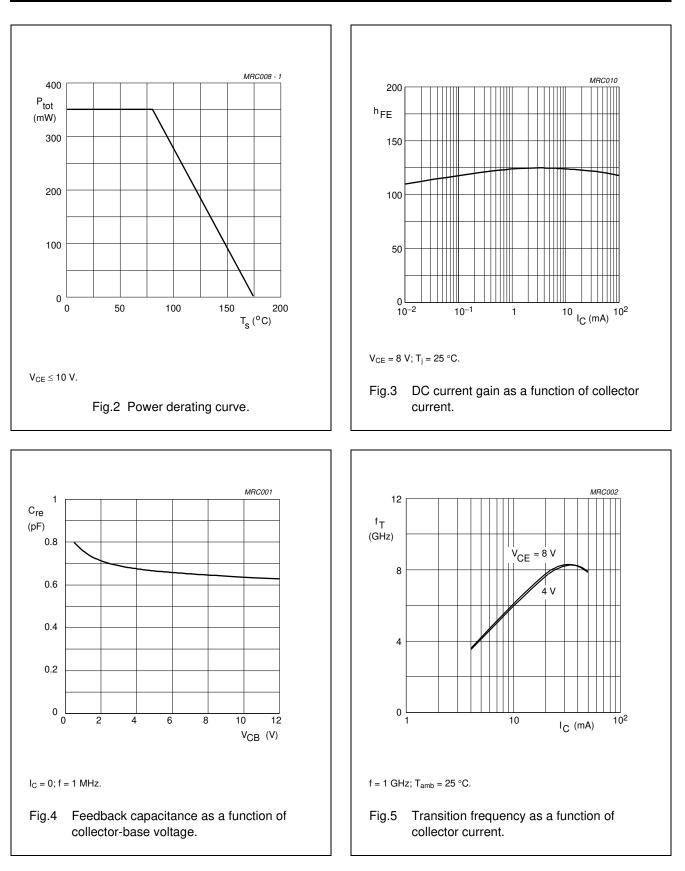
| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|------------------|--|---|------|------|------|------|
| I _{CBO} | collector cut-off current | I _E = 0; V _{CE} = 8 V | - | - | 50 | nA |
| h _{FE} | DC current gain | I _C = 40 mA; V _{CE} = 8 V | 100 | 120 | 250 | |
| Ce | emitter capacitance | $I_{C} = i_{c} = 0; V_{EB} = 0.5 V; f = 1 MHz$ | _ | 2 | - | pF |
| C _c | collector capacitance | $I_E = i_e = 0; V_{CB} = 8 V; f = 1 MHz$ | - | 0.9 | - | pF |
| C _{re} | feedback capacitance | $I_{C} = 0; V_{CB} = 8 V; f = 1 MHz$ | - | 0.6 | - | pF |
| f _T | transition frequency | $I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 1 \text{ GHz};$ $T_{amb} = 25 \text{ °C}$ | - | 9 | - | GHz |
| G _{UM} | maximum unilateral power gain (note 1) | $I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 900 \text{ MHz}; T_{amb} = 25 \text{ °C}$ | - | 14 | - | dB |
| | | $I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 2 \text{ GHz};$ $T_{amb} = 25 \text{ °C}$ | - | 8 | - | dB |
| $ s_{21} ^2$ | insertion power gain | $I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 900 \text{ MHz}; T_{amb} = 25 \text{ °C}$ | 12 | 13 | - | dB |
| F | noise figure | $\Gamma_{s} = \Gamma_{opt}$; I _C = 10 mA; V _{CE} = 8 V; f = 900 MHz; T _{amb} = 25 °C | - | 1.3 | 1.8 | dB |
| | | $\label{eq:Gamma} \begin{array}{l} \Gamma_{s}=\Gamma_{opt}; \ I_{C}=40 \ \text{mA}; \ V_{CE}=8 \ \text{V}; \\ f=900 \ \text{MHz}; \ T_{amb}=25 \ ^{\circ}\text{C} \end{array}$ | - | 1.9 | 2.4 | dB |
| | | $\label{eq:GHZ} \begin{split} \Gamma_{s} &= \Gamma_{opt}; \ I_{C} = 10 \ \text{mA}; \ V_{CE} = 8 \ \text{V}; \\ f &= 2 \ \text{GHz}; \ T_{amb} = 25 \ ^{\circ}\text{C} \end{split}$ | - | 2.1 | - | dB |
| P _{L1} | output power at 1 dB gain compression | I_c = 40 mA; V _{CE} = 8 V; R _L = 50 Ω; f = 900 MHz; T _{amb} = 25 °C | - | 21 | _ | dBm |
| ITO | third order intercept point | note 2 | _ | 34 | _ | dBm |

Notes

1. G_{UM} is the maximum unilateral power gain, assuming s_{12} is zero and

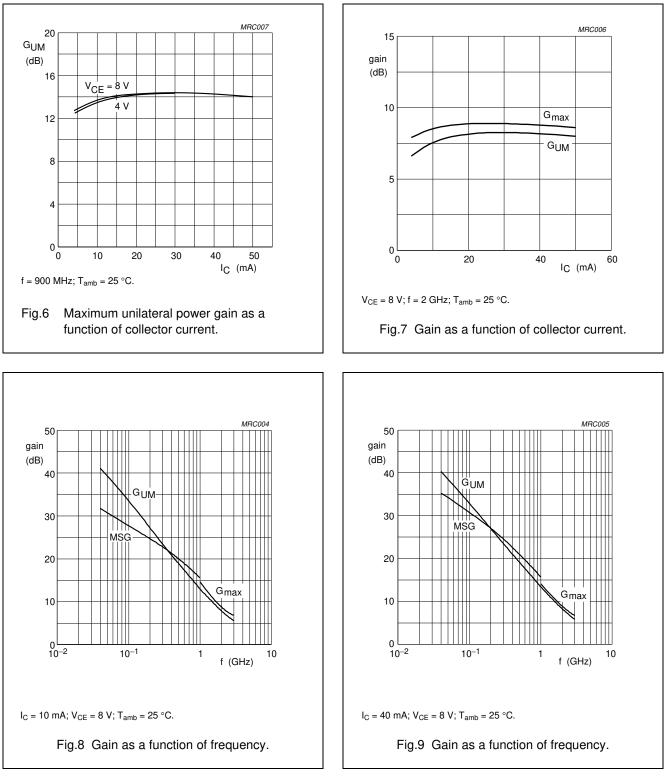
$$G_{UM} = 10 \log \frac{\left|s_{21}\right|^2}{(1 - \left|s_{11}\right|^2)(1 - \left|s_{22}\right|^2)} \ dB.$$

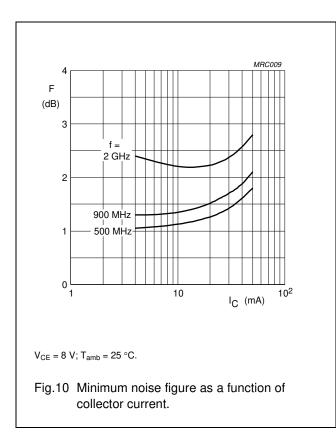
2. $I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; R_{L} = 50 \Omega; f = 900 \text{ MHz}; T_{amb} = 25 \text{ °C};$ $f_{p} = 900 \text{ MHz}; f_{q} = 902 \text{ MHz};$ measured at $f_{(2p-q)} = 898 \text{ MHz}$ and at $f_{(2q-p)} = 904 \text{ MHz}.$

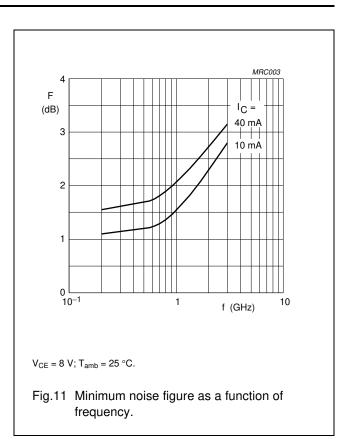


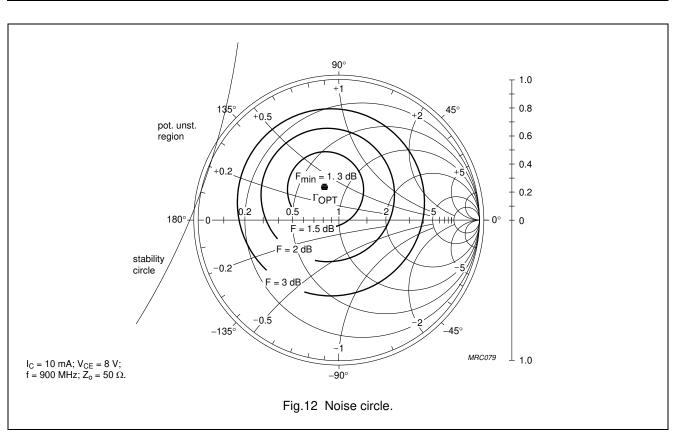
BFS540

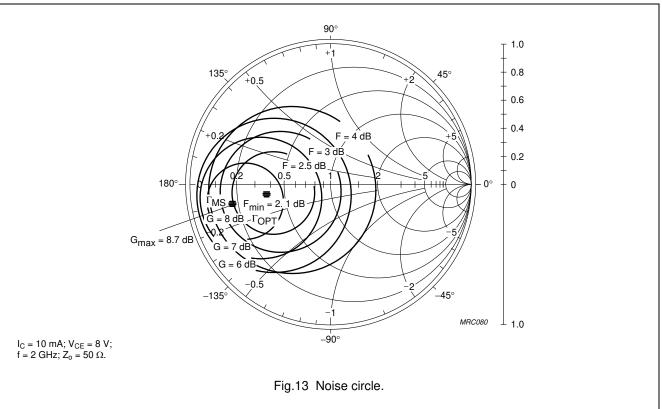
In Figs 6 to 9, G_{UM} = maximum unilateral power gain; MSG = maximum stable gain; G_{max} = maximum available gain.

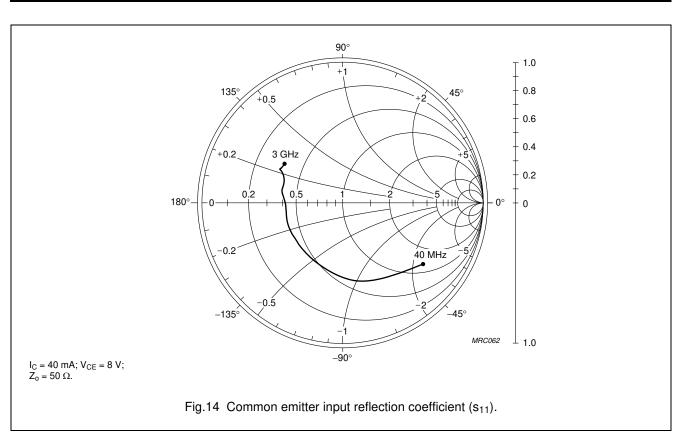


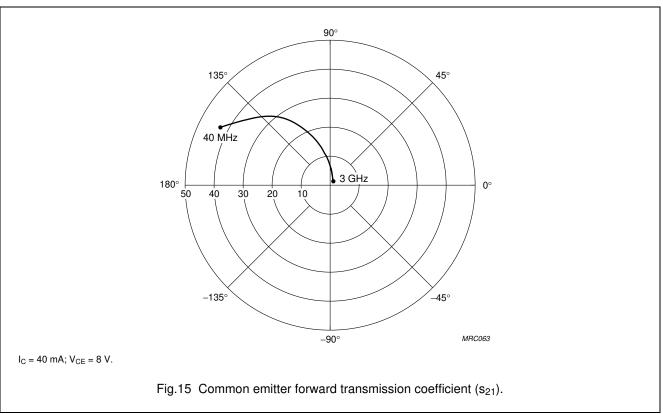


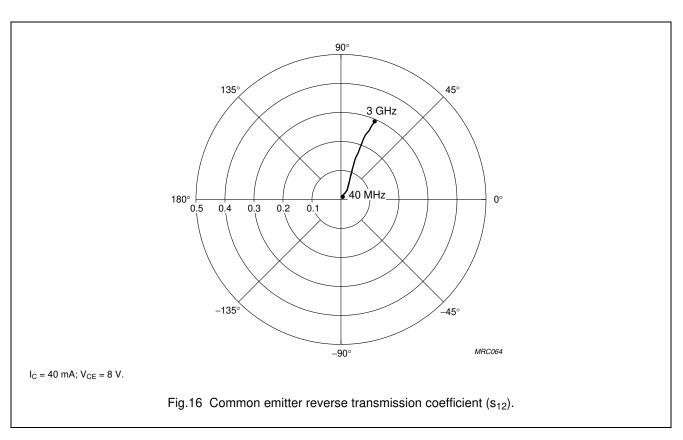


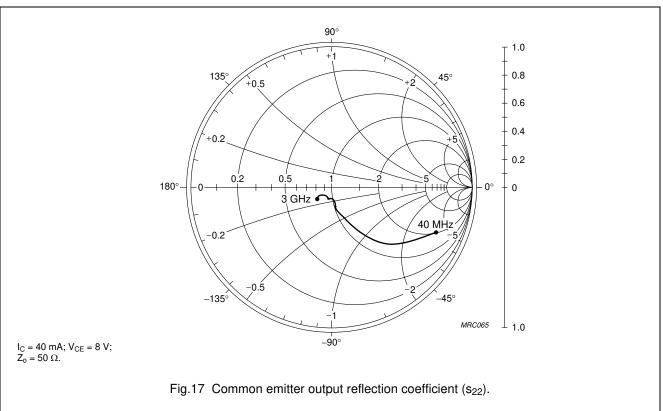




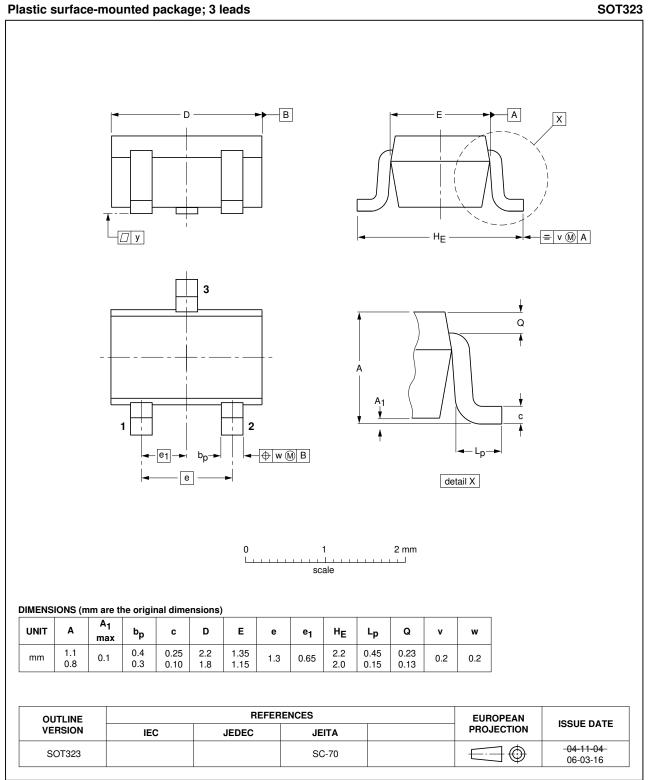








PACKAGE OUTLINE



BFS540

| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|-----------------------------------|----------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

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